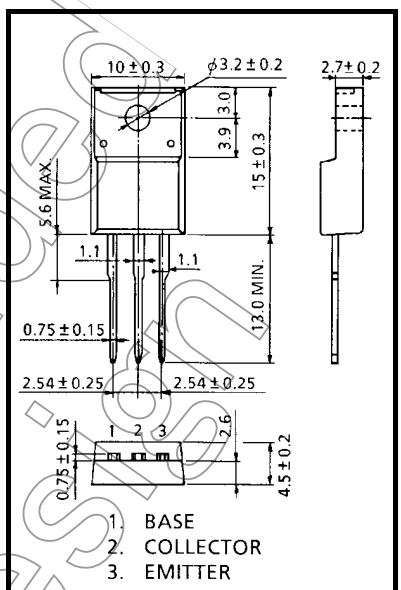
TOSHIBA Transistor Silicon NPN Triple Diffused Type (Darlington)

2SD2129

High-Power Switching Applications
Hammer Drive, Pulse Motor Drive Applications

- High DC current gain: h_{FE} = 2000 (min)
- Low saturation voltage: $V_{CE\ (sat)}$ = 1.5 V (max)

Unit: mm



JEDEC	—
JEITA	SC-67
TOSHIBA	2-10R1A

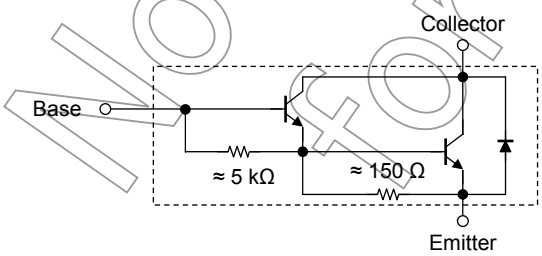
Weight: 1.7 g (typ.)

Absolute Maximum Ratings (Tc = 25°C)

Characteristics		Symbol	Rating	Unit
Collector-base voltage		V_{CBO}	100	V
Collector-emitter voltage		V_{CEO}	100	V
Emitter-base voltage		V_{EBO}	7	V
Collector current	DC	I_C	3	A
	Pulse	I_{CP}	5	
Base current		I_B	0.5	A
Collector power dissipation	Ta = 25°C	P_C	2.0	W
	Tc = 25°C		20	
Junction temperature		T_j	150	°C
Storage temperature range		T_{stg}	−55 to 150	°C

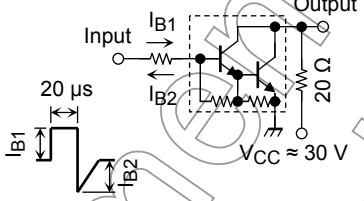
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Equivalent Circuit

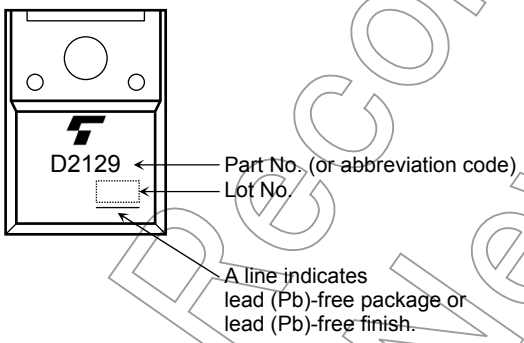


Not Recommended for New Design

Electrical Characteristics (Tc = 25°C)

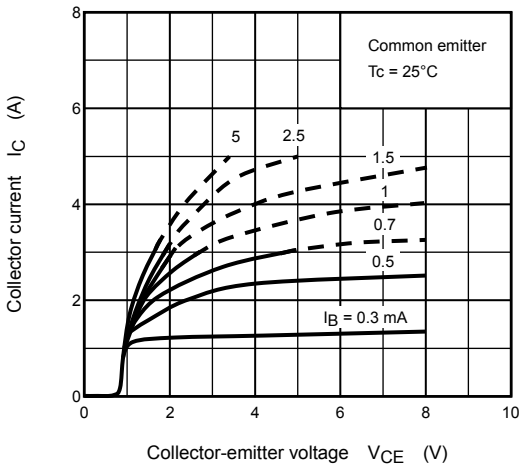
Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current		I_{CBO}	V_{CB} = 100 V, I_E = 0	—	—	100	μA
Emitter cut-off current		I_{EBO}	V_{EB} = 6 V, I_C = 0	—	—	2.5	mA
Collector-emitter breakdown voltage		$V_{(BR)\ CEO}$	I_C = 30 mA, I_B = 0	100	—	—	V
DC current gain		$h_{FE\ (1)}$	V_{CE} = 3 V, I_C = 1.5 A	2000	—	15000	
		$h_{FE\ (2)}$	V_{CE} = 3 V, I_C = 3 A	1000	—	—	
Collector-emitter saturation voltage		$V_{CE\ (sat)\ (1)}$	I_C = 1.5 A, I_B = 3 mA	—	—	1.5	V
		$V_{CE\ (sat)\ (2)}$	I_C = 3 A, I_B = 12 mA	—	—	2.0	
Base-emitter saturation voltage		$V_{BE\ (sat)}$	I_C = 1.5 A, I_B = 3 mA	—	—	2.0	V
Switching time	Turn-on time	t_{on}		—	1.0	—	μs
	Storage time	t_{stg}		—	5.0	—	
	Fall time	t_f		—	2.0	—	
			$I_{B1} = -I_{B2}$ = 3 mA, duty cycle ≤ 1%				

Marking

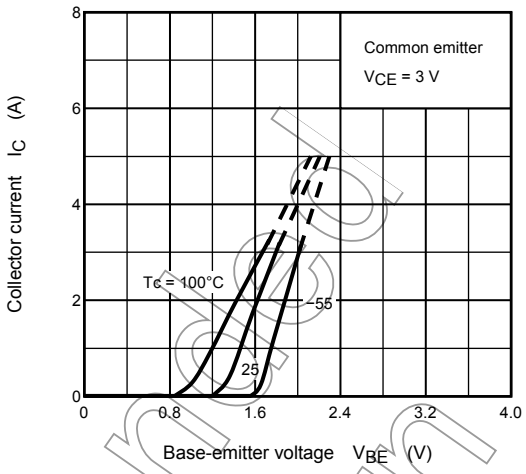


Not Recommended for New Design

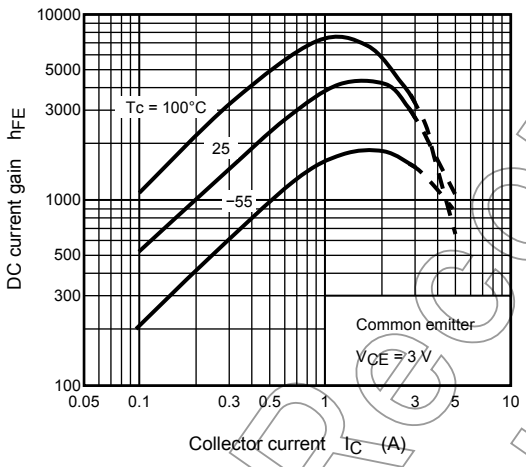
$I_C - V_{CE}$



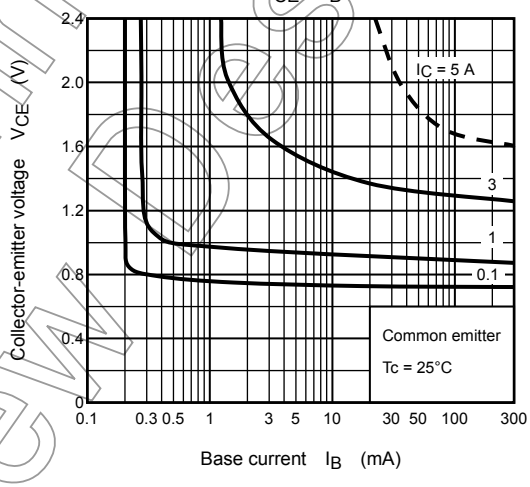
$I_C - V_{BE}$



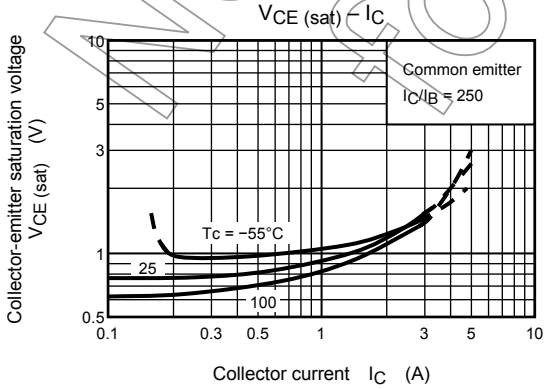
$h_{FE} - I_C$



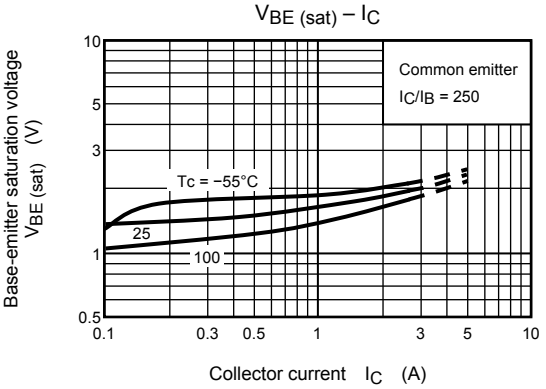
$V_{CE} - I_B$



$V_{CE\ (sat)} - I_C$

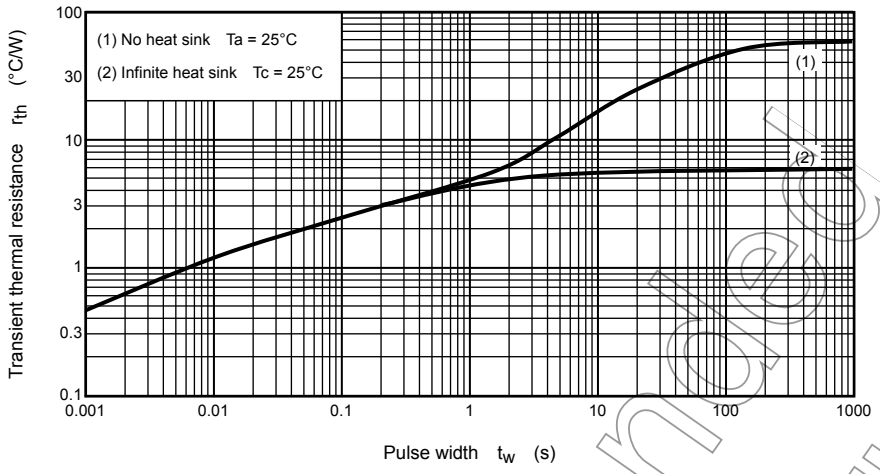


$V_{BE\ (sat)} - I_C$

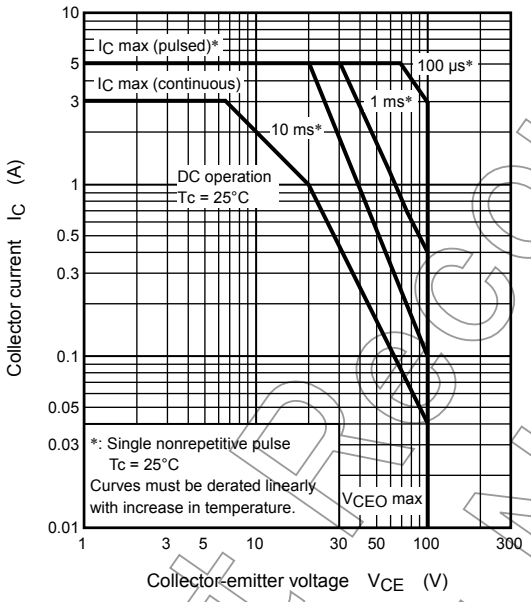


Not Recommended for New Design

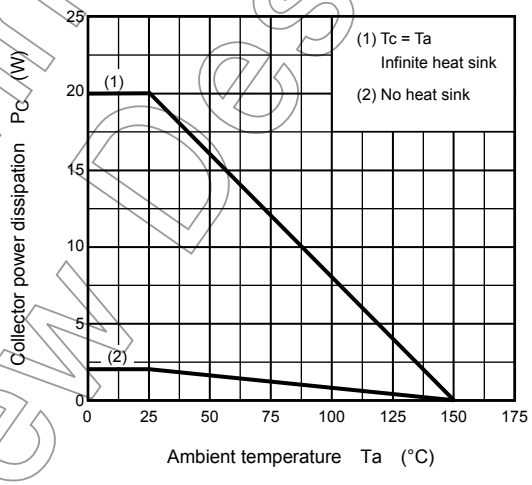
$r_{th} - t_w$



Safe Operating Area



$P_C - Ta$



Not Recommended for New Design

Not Recommended for New Design

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20070701-EN

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